

APPLICATION NO.

10/677,007

27518

UNITED STATES PATENT AND TRADEMARK OFFICE

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EXAMINER

TALBOT, BRIAN K

ART UNIT PAPER NUMBER
1762

DATE MAILED: 05/31/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

FIRST NAMED INVENTOR

Tingkai Li

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		Application No.	Applicant(s)		7
	055-14-55-10	10/677,007	LI ET AL.		
	Office Action Summary	Examiner	Art Unit	· · -	
·	Brian K. Talbot	1762			
Period f	The MAILING DATE of this communication app or Reply	pears on the cover sheet w	ith the correspondence addre	SS	
THE - Extended - If the - If NO - Faile Any	MORTENED STATUTORY PERIOD FOR REPL' MAILING DATE OF THIS COMMUNICATION. ensions of time may be available under the provisions of 37 CFR 1.1 r SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a reply D period for reply is specified above, the maximum statutory period v ure to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing led patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a i y within the statutory minimum of thir will apply and will expire SIX (6) MON , cause the application to become At	reply be timely filed ty (30) days will be considered timely. ITHS from the mailing date of this comm BANDONED (35 U.S.C. § 133).	unication.	
Status					
1)🛛	Responsive to communication(s) filed on 30 S	eptember 2003.			
2a)[☐	This action is FINAL . 2b)⊠ This	action is non-final.			
3)□	Since this application is in condition for alloware closed in accordance with the practice under <i>E</i>	•	· •	erits is	į
Disposit	ion of Claims				
5)[Claim(s) <u>1-16</u> is/are pending in the application 4a) Of the above claim(s) is/are withdray Claim(s) is/are allowed. Claim(s) <u>1-16</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or	wn from consideration.			
Applicat	ion Papers				
9)[The specification is objected to by the Examine	er.			
10)[epted or b) objected to			
	Applicant may not request that any objection to the		` '		
11)□	Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	,	` '	` ,	
		tarmier. Note the attached	3 Office Action of Toffit 1 TO-	102.	
_	under 35 U.S.C. § 119	adadu, undan 65 H 6 6 3			
	Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureau	s have been received. s have been received in A rity documents have been	pplication No	nge	
* ;	See the attached detailed Office action for a list	• • • • • • • • • • • • • • • • • • • •	received.		
Attachmer	nt(s)				
1) 🔯 Notic	ce of References Cited (PTO-892)	4) Interview S	Summary (PTO-413)		
3) Infor	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date		s)/Mail Date nformal Patent Application (PTO-15 	2)	

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1. Claims 1-16 remain in the application.

Claim Rejections - 35 USC § 112

2. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 1-16 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The term "thin" in claims 1 and 9 is a relative term that renders the claim indefinite. The term "thin" is not defined by the claim, the specification does not provide a standard for ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention. The term "completing" is vague and indefinite. In is unclear what the term "completing" encompasses.

With respect to claims 2,3,10 and 11, the phrase "said preparing step includes forming an oxide layer/high-k oxide on the silicon substrate" is confusing. Should this recite in the "depositing" step or is there an oxide layer formed first and then atop this layer an indium-containing layer is formed? Clarification is requested.

The term "high-k" in claim 3 and 11 is a relative term that renders the claim indefinite.

The term "high-k" is not defined by the claim, the specification does not provide a standard for

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ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention.

With respect to claim 5 and 13, the phrase "forming a silica dioxide trench structure" is unclear. How is this performed from etching the indium-containing film? Where does the "silicon dioxide" comp from when the substrate is silicon and the coating is indium-containing? Claims 4,6-9,12 and 14-16 are rejected as being dependent upon a rejected base claim.

Double Patenting

3. Claims 1-16 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1-18 of copending Application No. 10/676,983 and claims 1-19 of copending Application No. 10/780,919.

Although the conflicting claims are not identical, they are not patentably distinct from each other because the claims recite forming an indium oxide film on a silicon substrate, etching or patterning the indium oxide film, forming a ferroelectric film of PGO thereon, and completing the device.

This is a <u>provisional</u> obviousness-type double patenting rejection because the conflicting claims have not in fact been patented.

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Claim Rejections - 35 USC § 103

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4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all

obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are

such that the subject matter as a whole would have been obvious at the time the invention was made to a person

having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the

manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the

claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various

claims was commonly owned at the time any inventions covered therein were made absent any

evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out

the inventor and invention dates of each claim that was not commonly owned at the time a later

invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c)

and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1-5 and 9-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Li et

al. (6,825,519) in combination with Shepherd (5,003,428).

Li et al. (6,825,519) teaches selectively depositing PGO thin film to form a ferroelectric

device. A silicon oxide layer is formed on a silicon substrate, a bottom electrode is formed and

patterned thereon, a PGO layer is applied, annealed and a top electrode is formed to complete

the device (abstract, col. 1, lines 40-60).

Li et al. (6,825,519) fails to teach a patterned indium oxide layer as the bottom electrode.

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Shepherd (5,003,428) teaches electrodes for ceramic oxide capacitors. Shepherd (5,003,428) teaches that indium oxide and indium tin oxide are used as materials for thin film ferroelectric ceramic capacitors (col. 2, lines 40-50).

Therefore it would have been obvious for one skilled in the art at the time the invention was made to have substituted the electrode material of Li et al. (6,825,519) process by incorporating indium oxide for the electrode material as evidenced Shepherd (5,003,428) with the expectation of achieving similar success.

Claims 7,8,15 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Li et al. (6,825,519) in combination with Shepherd (5,003,428) further in combination with Li et al. (6,664,116).

Features described above are incorporated here.

Li et al. (6,825,519) in combination with Shepherd (5,003,428) fail to teach the claimed processing parameters for forming the PGO film.

Li et al. (6,664,116) teaches the claimed processing parameters for forming the PGO film (col. 2, line 10 – col. 3, line 50).

Therefore it would have been obvious for one skilled in the art at the time the invention was made to have modified Li et al. (6,825,519) in combination with Shepherd (5,003,428) by forming the PGO film as detailed by Li et al. (6,664,116) with the expectation of achieving similar results.

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Claims 6 and 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Li et al. (6,825,519) in combination with Shepherd (5,003,428).

Features described above are incorporated here.

Li et al. (6,825,519) in combination with Shepherd (5,003,428) fail to teach the claimed processing parameters for forming the In2O3 film.

While the Examiner acknowledges this fact, it is the Examiner's position that sputtering indium oxide films are conventional in the art and the processing parameters would be a matter of design choice of one practicing in the art dependent upon the desired final product.

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Brian K. Talbot whose telephone number is (571) 272-1428. The examiner can normally be reached on Monday-Friday 6AM-3PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy H. Meeks can be reached on (571) 272-1423. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Brian K Talbot Primary Examiner Art Unit 1762

BKT